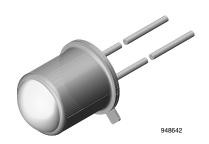
### Vishay Semiconductors



## Silicon PIN Photodiode, RoHS Compliant



# DESCRIPTION

BPW24R is a high sensitive silicon planar photodiode in a standard TO-18 hermetically sealed metal case with a glass lens.

A precise alignment of the chip gives a good coincidence of mechanical and optical axes. The device features a low capacitance and high speed even at low supply voltages.

### **FEATURES**

Package type: leadedPackage form: TO-18

• Dimensions (in mm): Ø 4.7

Radiant sensitive area (in mm<sup>2</sup>): 0.78

· High photo sensitivity

· High radiant sensitivity

• Suitable for visible and near infrared radiation

· Fast response times

• Angle of half sensitivity:  $\varphi = \pm 12^{\circ}$ 

· Hermetically sealed package

· Cathode connected to package

· Central chip alignment

 Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC

### **APPLICATIONS**

· High speed photo detector

PRODUCT SUMMARY				
COMPONENT	I <sub>ra</sub> (μΑ)	φ (deg)	λ <sub>0.5</sub> (nm)	
BPW24R	60	± 12	600 to 1050	

#### Note

Test condition see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
BPW24R	Bulk	MOQ: 1000 pcs, 1000 pcs/bulk	TO-18	

#### Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	60	V	
Power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>V</sub>	210	mW	
Junction temperature		Tj	125	°C	
Operating temperature range		T <sub>amb</sub>	- 40 to + 125	°C	
Storage temperature range		T <sub>stg</sub>	- 40 to + 125	°C	
Soldering temperature	t ≤ 5 s	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm <sup>2</sup>	R <sub>thJA</sub>	350	K/W	

#### Note

T<sub>amb</sub> = 25 °C, unless otherwise specified





RoHS

### Silicon PIN Photodiode, RoHS Compliant

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BASIC CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Breakdown voltage	I <sub>R</sub> = 100 μA, E = 0	V <sub>(BR)</sub>	60	200		V
Reverse dark current	V <sub>R</sub> = 50 V, E = 0	I <sub>ro</sub>		2	10	nA
Diode capacitance	V <sub>R</sub> = 0 V, f = 1 MHz, E = 0	C <sub>D</sub>		11		pF
	V <sub>R</sub> = 5 V, f = 1 MHz, E = 0	C <sub>D</sub>		3.8		pF
	V <sub>R</sub> = 20 V, f = 1 MHz, E = 0	C <sub>D</sub>		2.5		pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	Vo		450		mV
Temperature coefficient of Vo	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	$TK_Vo$		- 2		mV/K
Short circuit current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	I <sub>k</sub>		55		μΑ
Temperature coefficient of I <sub>k</sub>	E <sub>A</sub> = 1 klx	TK <sub>lk</sub>		0.1		%/K
Reverse light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}, \ V_R = 20 \text{ V}$	I <sub>ra</sub>	45	60		μΑ
Absolute Spectral Sensitivity	V <sub>R</sub> = 5 V, λ = 870 nm	s(λ)		0.60		A/W
	$V_R = 5 \text{ V}, \ \lambda = 900 \text{ nm}$	s(λ)		0.55		A/W
Angle of half sensitivity		φ		± 12		deg
Wavelength of peak sensitivity		$\lambda_{p}$		900		nm
Range of spectral bandwidth		λ <sub>0.5</sub>		600 to 1050		nm
Rise time	$V_R = 20 \text{ V}, R_L = 50 \Omega, \lambda = 820 \text{ nm}$	t <sub>r</sub>		7		ns
Fall time	$V_R = 20 \text{ V}, R_L = 50 \Omega, \lambda = 820 \text{ nm}$	t <sub>f</sub>		7		ns

#### Note

 $T_{amb}$  = 25 °C, unless otherwise specified

### **BASIC CHARACTERISTICS**

 $T_{amb}$  = 25 °C, unless otherwise specified

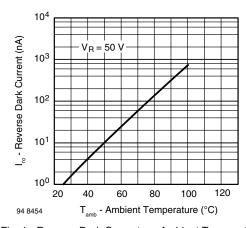


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

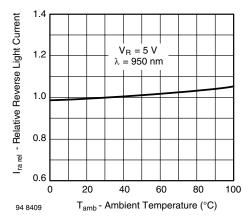


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

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### Silicon PIN Photodiode, RoHS Compliant



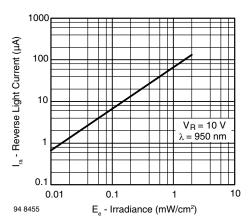


Fig. 3 - Reverse Light Current vs. Irradiance

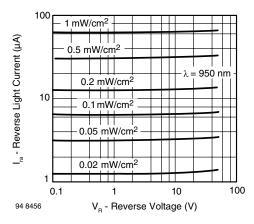


Fig. 4 - Reverse Light Current vs. Reverse Voltage

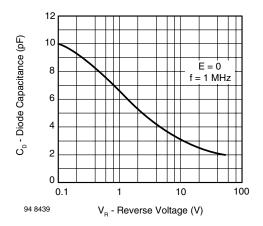


Fig. 5 - Diode Capacitance vs. Reverse Voltage

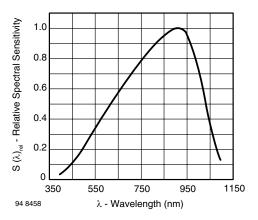


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

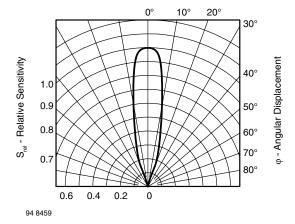
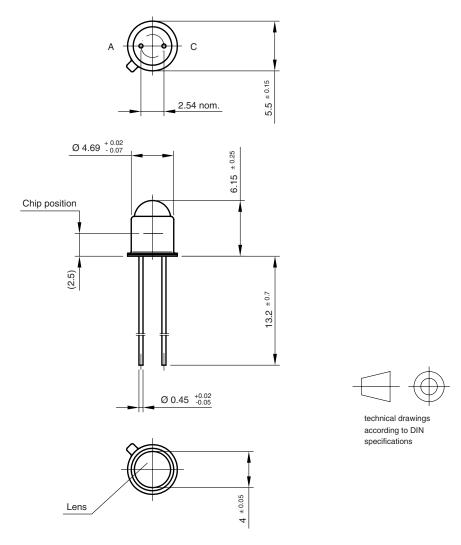


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement



## Silicon PIN Photodiode, RoHS Compliant

### **PACKAGE DIMENSIONS** in millimeters



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